

60 V, 300 mA dual N-channel Trench MOSFET

Rev. 2 — 23 September 2010

Product data sheet

1. Product profile

1.1 General description

Dual N-channel enhancement mode Field-Effect Transistor (FET) in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

1.2 Features and benefits

- Logic-level compatible
- Very fast switching
- Trench MOSFET technology
- ESD protection up to 2 kV
- AEC-Q101 qualified

1.3 Applications

- Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits

1.4 Quick reference data

Table 1.Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DS}	drain-source voltage	$T_{amb} = 25 \ ^{\circ}C$	-	-	60	V
V_{GS}	gate-source voltage	T _{amb} = 25 °C	-	-	±20	V
I _D	drain current	$T_{amb} = 25 \text{ °C};$ $V_{GS} = 10 \text{ V}$	<u>[1]</u> -	-	300	mA
R _{DSon}	drain-source on-state resistance	T _j = 25 °C; V _{GS} = 10 V; I _D = 500 mA	-	1	1.6	Ω

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

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2. Pinning information

Table 2.	Pinning			
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S1	source 1		
2	G1	gate 1		
3	D2	drain 2		
4	S2	source 2		
5	G2	gate 2		2 5
6	D1	drain 1		

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3. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
2N7002BKS	SC-88	plastic surface-mounted package; 6 leads	SOT363			

4. Marking

Table 4.	Marking codes	
Type nur	nber	Marking code ^[1]
2N7002B	KS	ZT*

[1] * = -: made in Hong Kong

* = p: made in Hong Kong

* = t: made in Malaysia

* = W: made in China

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

		0,00	,		
Symbol	Parameter	Conditions	Min	Max	Unit
Per trans	istor				
V _{DS}	drain-source voltage	T _{amb} = 25 °C	-	60	V
V_{GS}	gate-source voltage	T _{amb} = 25 °C	-	±20	V
I _D	drain current	$V_{GS} = 10 V$	<u>[1]</u>		
		$T_{amb} = 25 \ ^{\circ}C$	-	300	mA
		T _{amb} = 100 °C	-	215	mA

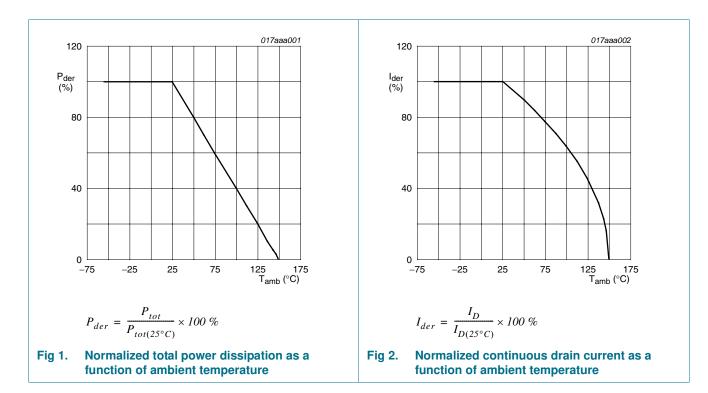
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In accordance with the Absolute Maximum Rating System (IEC 60134). Symbol Parameter Conditions Min Max Unit peak drain current $T_{amb} = 25 \circ C;$ 1.2 А I_{DM} single pulse; $t_p \le 10 \ \mu s$ [2] _ P_{tot} T_{amb} = 25 °C 295 mW total power dissipation [1] _ 340 mW T_{sp} = 25 °C 1040 mW -Source-drain diode [1] _ T_{amb} = 25 °C 300 mΑ ls source current ESD maximum rating [3] _ 2000 ٧ electrostatic discharge human body model VESD voltage Per device [2] _ total power dissipation T_{amb} = 25 °C 445 mW P_{tot} 150 °C Ti junction temperature ambient temperature -55 +150 °C Tamb storage temperature -65 +150 °C T_{stg}

 Table 5.
 Limiting values ... continued

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

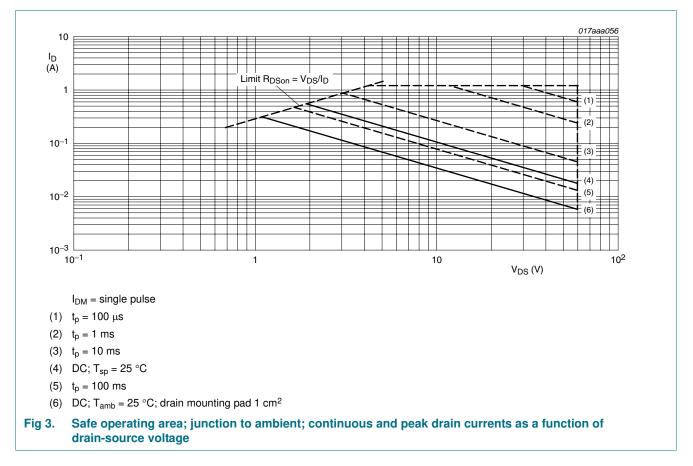
[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



[3] Measured between all pins.

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6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Per transis	stor					
$R_{th(j\text{-}a)}$	thermal resistance from junction to ambient	in free air	<u>[1]</u> -	370	425	K/W
			[2] _	320	370	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		-	-	120	K/W
Per device)					
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	<u>[1]</u> -	-	275	K/W

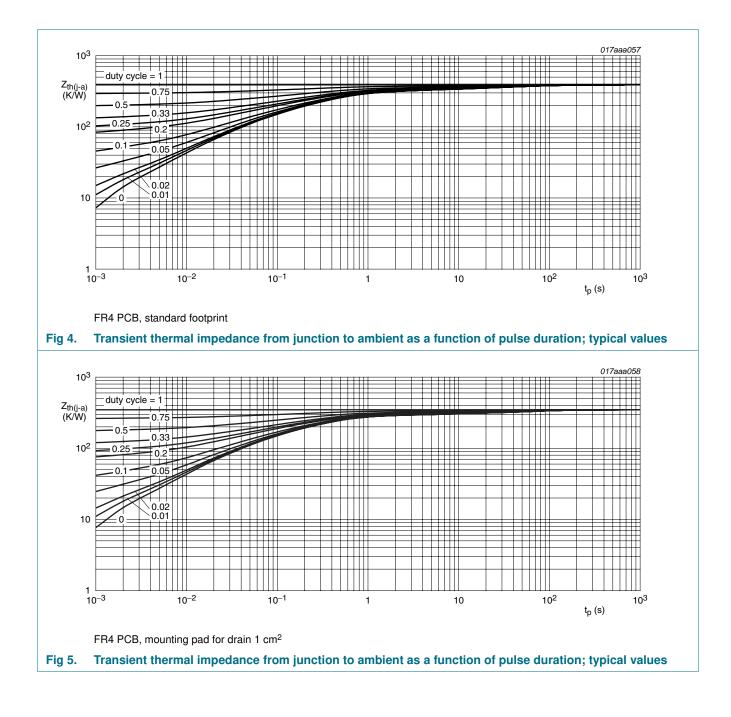
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

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7. Characteristics

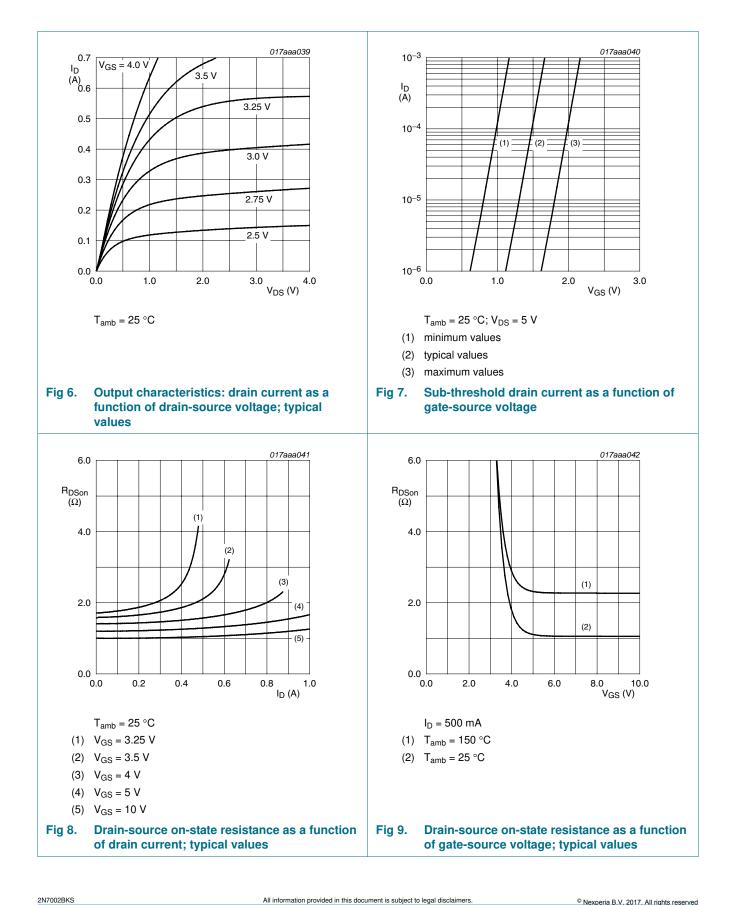
Table 7. <i>T_j</i> = 25 <i>°</i> C	Characteristics unless otherwise specified.					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 10 \ \mu\text{A}; \ V_{GS} = 0 \ V$	60	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 250 \ \mu\text{A}; \ V_{DS} = V_{GS}$	1.1	1.6	2.1	V
I _{DSS}	drain leakage current	$V_{DS} = 60 \text{ V}; V_{GS} = 0 \text{ V}$				
		T _j = 25 °C	-	-	1	μA
		T _j = 150 °C	-	-	10	μA
I _{GSS}	gate leakage current	$V_{GS}=\pm 20~V;~V_{DS}=0~V$	-	-	10	μA
R _{DSon}	drain-source on-state resistance		<u>[1]</u>			
		$V_{GS} = 5 \text{ V}; \text{ I}_{D} = 50 \text{ mA}$	-	1.3	2	Ω
		V_{GS} = 10 V; I _D = 500 mA	-	1	1.6	Ω
9 _{fs}	forward transconductance	$V_{DS} = 10 \text{ V}; I_D = 200 \text{ mA}$	<u>[1]</u> _	550	-	mS
Dynamic	characteristics					
Q _{G(tot)}	total gate charge	I _D = 300 mA;	-	0.5	0.6	nC
Q _{GS}	gate-source charge	[–] V _{DS} = 30 V; – V _{GS} = 4.5 V	-	0.2	-	nC
Q _{GD}	gate-drain charge	$-v_{GS} = 4.5 v$	-	0.1	-	nC
C _{iss}	input capacitance	$V_{GS} = 0 V; V_{DS} = 10 V;$	-	33	50	pF
C _{oss}	output capacitance	f = 1 MHz	-	7	-	pF
C _{rss}	reverse transfer capacitance		-	4	-	pF
t _{d(on)}	turn-on delay time	V _{DD} = 50 V;	-	5	10	ns
t _r	rise time	$R_{L} = 250 \Omega;$	-	6	-	ns
t _{d(off)}	turn-off delay time	– V _{GS} = 10 V; R _G = 6 Ω	-	12	24	ns
t _f	fall time	_	-	7	-	ns
Source-di	ain diode					
V _{SD}	source-drain voltage	I _S = 115 mA; V _{GS} = 0 V	0.47	0.75	1.1	V

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Product data sheet

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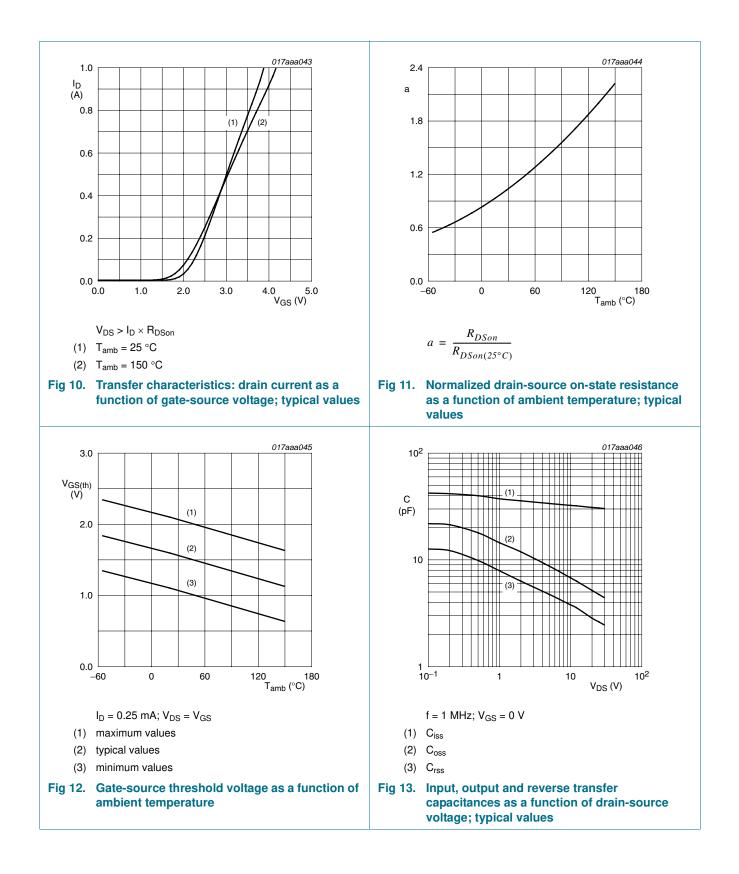
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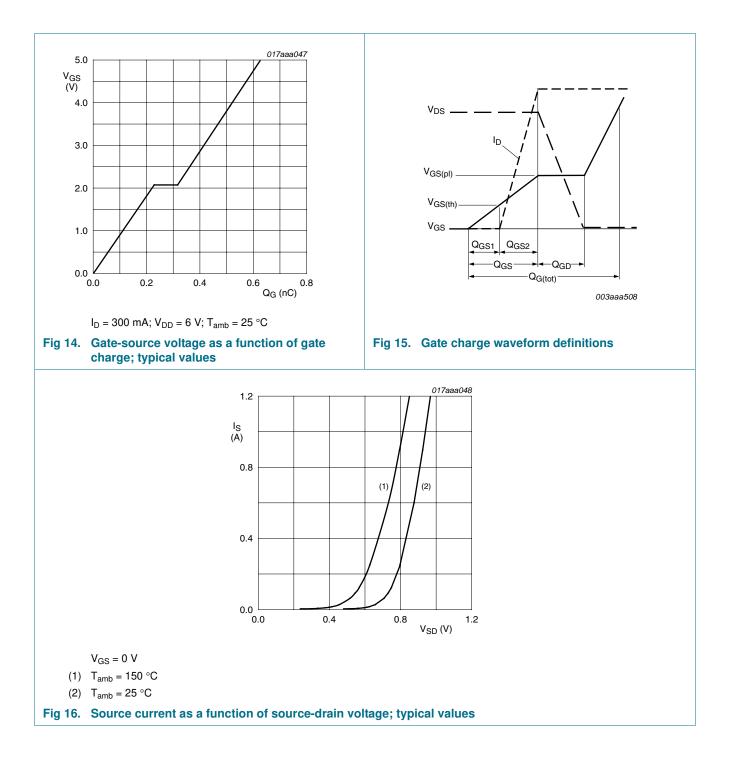
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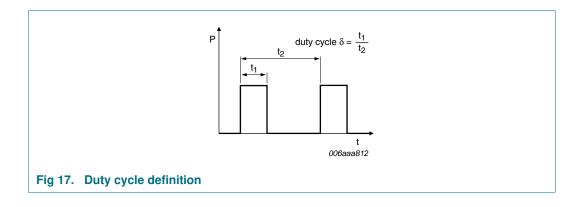
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8. Test information



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9. Package outline

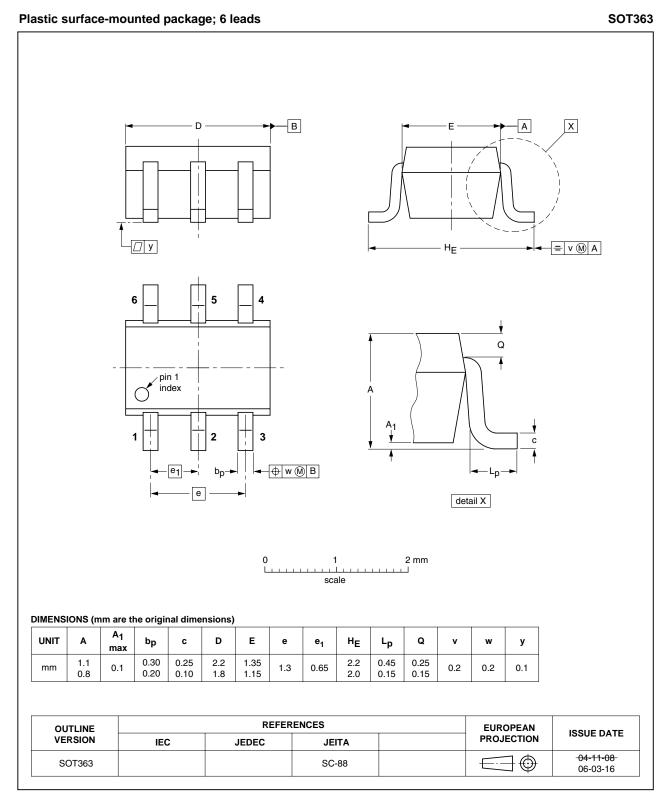
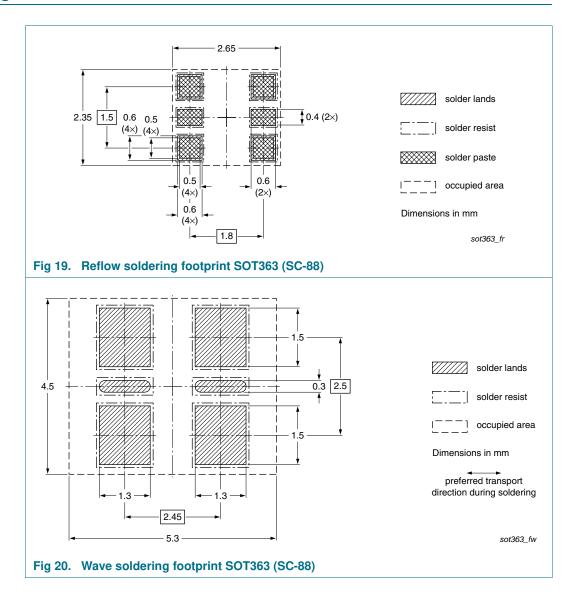


Fig 18. Package outline SOT363 (SC-88)

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10. Soldering



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11. Revision history

Table 8.	Revision histo	ory			
Documen	t ID	Release date	Data sheet status	Change notice	Supersedes
2N7002Bk	(S v.2	20100923	Product data sheet	-	2N7002BKS v.1
Modificatio	ons:	Table 2 "Pinn	ing": graphic symbol amended		
2N7002Bk	(S v.1	20100617	Product data sheet	-	-

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12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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